Product data sheet

1. General description

PNP/PNP matched double transistor in a very small Surface-Mounted Device (SMD) SOT363 (SC-88) plastic package. The transistors are fully isolated internally.

2. Features and benefits

- Current gain matching
- Base-emitter voltage matching
- Drop-in replacement for standard double transistors
- AEC-Q101 qualified

3. Applications

- Current mirror
- Differential amplifier

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor			•				
V _{CEO}	collector-emitter voltage	open base		-	-	-45	V
I _C	collector current			-	-	-100	mA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -2 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		200	290	450	
Per device			•				
h _{FE1} /h _{FE2}	DC current gain matching	V_{CE} = -5 V; I_{C} = -2 mA; T_{amb} = 25 °C	[1]	0.9	1	-	
V _{BE1} -V _{BE2}	base-emitter voltage matching		[2]	-	-	2	mV

^[1] The smaller of the two values is taken as the numerator.

^[2] The smaller of the two values is subtracted from the larger value.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	Пе Пе Пи	C1 B2 E2
2	B1	base TR1	6 5 4	
3	C2	collector TR2		(TR1)
4	E2	emitter TR2		
5	B2	base TR2	☐1 ☐2 ☐3	E1 B1 C2
6	C1	collector TR1	TSSOP6 (SOT363)	sym018

6. Ordering information

Table 3. Ordering information

Type number	er Package					
	Name	Description	Version			
BCM857BS		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
BCM857BS	A9%

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transisto	r		,			
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V _{CEO}	collector-emitter voltage	open base		-	-45	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
I _C	collector current			-	-100	mA
I _{CM}	peak collector current	t _p ≤ 1 ms; single pulse		-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or		•				
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device					'		
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

10. Characteristics

Table 7. Characteristics

Parameter	Conditions		Min	Тур	Max	Unit
r					_	
collector-base cut-off	V _{CB} = -30 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-15	nA
current	V _{CB} = -30 V; I _E = 0 A; T _j = 150 °C		-	-	-5	μA
emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-100	nA
DC current gain	V _{CE} = -5 V; I _C = -10 μA; T _{amb} = 25 °C		-	250	-	
	V_{CE} = -5 V; I_{C} = -2 mA; T_{amb} = 25 °C		200	290	450	
collector-emitter	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C		-	-50	-200	mV
saturation voltage	I_C = -100 mA; I_B = -5 mA; T_{amb} = 25 °C		-	-200	-400	mV
base-emitter saturation	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C	[1]	-	-760	-	mV
voltage	I_C = -100 mA; I_B = -5 mA; T_{amb} = 25 °C	[1]	-	-920	-	mV
base-emitter voltage	V_{CE} = -5 V; I_{C} = -2 mA; T_{amb} = 25 °C	[2]	-600	-650	-700	mV
	V_{CE} = -5 V; I_{C} = -10 mA; T_{amb} = 25 °C	[2]	-	-	-760	mV
collector capacitance	V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	2.2	pF
emitter capacitance	V_{EB} = -0.5 V; I_{C} = 0 A; i_{c} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	10	-	pF
transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C		100	175	-	MHz
noise figure	V_{CE} = -5 V; I_{C} = -0.2 mA; R_{S} = 2 k Ω ; f = 10 kHz to 15.7 kHz		-	1.6	-	dB
	V _{CE} = -5 V; I _C = -0.2 mA; f = 1 kHz; B = 200 Hz		-	3.1	-	dB
1	1					
DC current gain matching	V_{CE} = -5 V; I_{C} = -2 mA; T_{amb} = 25 °C	[3]	0.9	1	-	
base-emitter voltage matching		[4]	-	-	2	mV
	collector-base cut-off current emitter-base cut-off current DC current gain collector-emitter saturation voltage base-emitter voltage base-emitter voltage collector capacitance emitter capacitance transition frequency noise figure DC current gain matching base-emitter voltage	$ \begin{array}{ c c c } \hline \\ \text{collector-base cut-off} \\ \text{current} \\ \hline \\ $	$ \begin{array}{ c c c c } \hline & \text{collector-base cut-off} \\ \hline & \text{current} \\ \hline & & & & & & & & & & & & & & & & & &$	$ \begin{array}{ c c c c } \hline & \text{collector-base cut-off} \\ \hline & \text{current} \\ \hline & \text{collector-base cut-off} \\ \hline & \text{current} \\ \hline & \text{V}_{CB} = -30 \text{ V}; \text{ I}_{E} = 0 \text{ A}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CB} = -30 \text{ V}; \text{ I}_{E} = 0 \text{ A}; \text{ T}_{j} = 150 \text{ °C} \\ \hline & \text{V}_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -10 \text{ µA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -2 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -2 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -10 \text{ mA}; \text{ I}_{B} = -0.5 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -100 \text{ mA}; \text{ I}_{B} = -0.5 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -100 \text{ mA}; \text{ I}_{B} = -0.5 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -2 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -2 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -10 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -10 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -10 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -10 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -10 \text{ mA}; \text{ T}_{amb} = 25 \text{ °C} \\ \hline & \text{V}_{CE} = -5 \text{ V}; \text{ I}_{C} = -0 \text{ A}; \text{ I}_{c} = 0 $	$ \begin{array}{ c c c c } \hline \\ collector-base cut-off current \\ \hline \\ current \\ current \\ \hline \\ current \\ current \\ \hline \\ current \\ cur$	$ \begin{array}{ c c c c } \hline \\ collector-base cut-off current \\ \hline \\ current \\ current \\ \hline \\ current \\ current \\ \hline \\ current \\ c$

 V_{BEsat} decreases by about 1.7 mV/K with increasing temperature. V_{BE} decreases by about 2 mV/K with increasing temperature. The smaller of the two values is taken as the numerator.

The smaller of the two values is subtracted from the larger value.

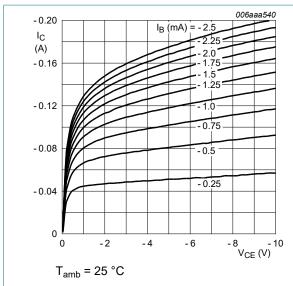
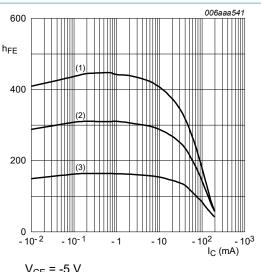


Fig. 1. Collector current as a function of collectoremitter voltage; typical values



V_{CE} = -5 V (1) T_{amb} = 100 °C (2) T_{amb} = 25 °C (3) T_{amb} = -55 °C

Fig. 2. DC current gain as a function of collector current; typical values

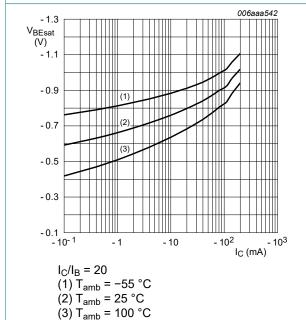
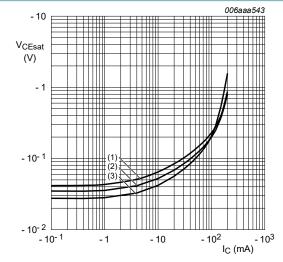


Fig. 3. Base-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 20$ (1) $T_{\rm amb} = 100~{\rm ^{\circ}C}$ (2) $T_{\rm amb} = 25~{\rm ^{\circ}C}$ (3) $T_{\rm amb} = -55~{\rm ^{\circ}C}$

Fig. 4. Collector-emitter saturation voltage as a function of collector current; typical values

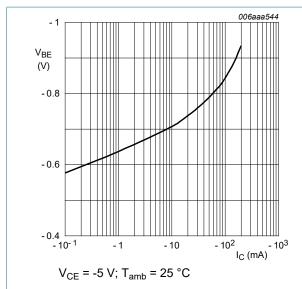
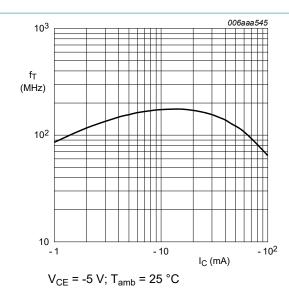
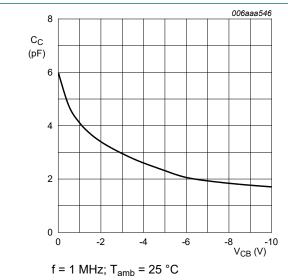


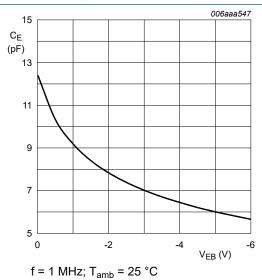
Fig. 5. Base-emitter voltage as a function of collector current; typical values



Transition frequency as a function of collector Fig. 6. current; typical values



Collector capacitance as a function of collector- Fig. 8. base voltage; typical values



Emitter capacitance as a function of emitterbase voltage; typical values

11. Application information

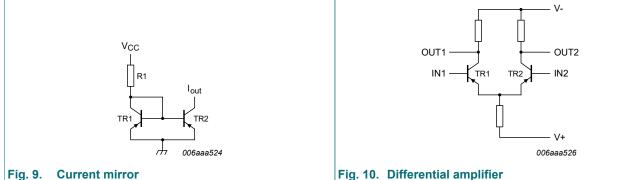
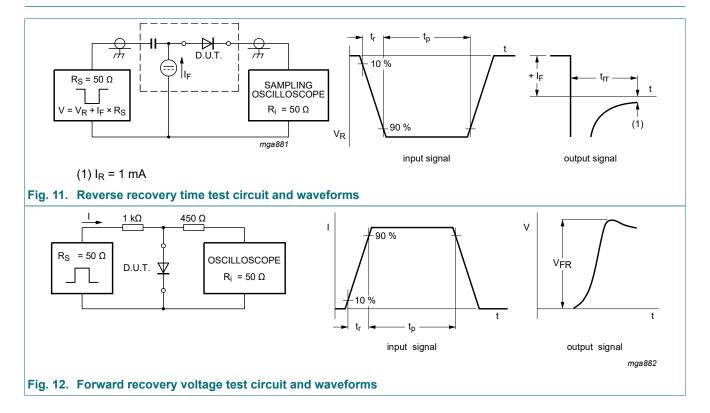


Fig. 10. Differential amplifier **Current mirror**

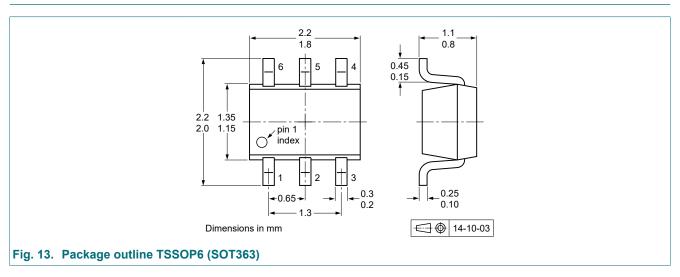
12. Test information



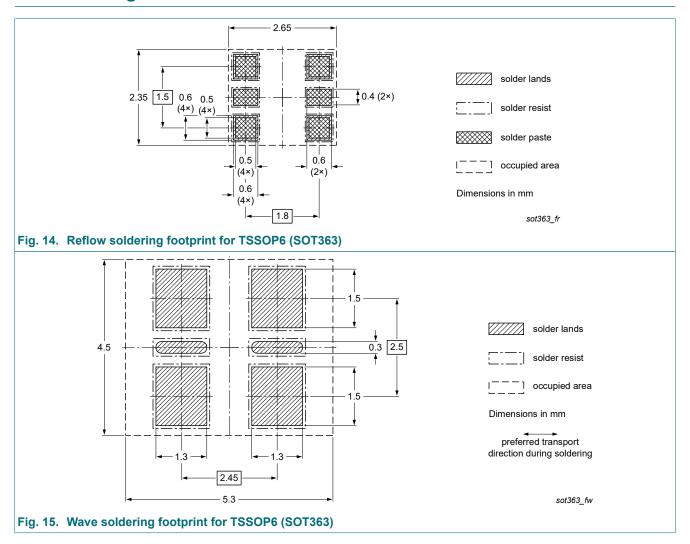
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

13. Package outline



14. Soldering



15. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
BCM857BS v.7	20230704	Product data sheet	-	BCM857BV_BS_DS_6			
Modifications:	Nexperia. Legal texts have bee Family data sheet sp	Legal texts have been adapted to the new company name where appropriate.					
BCM857BV_BS_DS_6	20090828			BCM857BV_BS_DS_5			
BCM857BV_BS_DS_5	20060627	Product data sheet	-	BCM857BS_DS_4			
BCM857BS_DS_4	20060216	Product data sheet	-	BCM857BS_DS_3			
BCM857BS_DS_3	20060130	Product data sheet	-	BCM857BS_2			
BCM857BS_2	20050411	Product data sheet	-	BCM857BS_1			
BCM857BS_1	20040914	Product data sheet	-	-			

16. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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BCM857BS

PNP/PNP matched double transistor

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